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Substitut	for form 1449A/PTO			С	omplete if Known
INFO	RMATION I	מופכי	LOSTIRE	Application Number	Based on 09/714,891
	EMENT BY			Filing Date	November 17, 2000
SIA		-		First Named Inventor	Koji ONO et al.
	(use as many sheets t	as necessi	2 <i>T</i> Y)	Group Art Unit	2815
				Examiner Name	Jerome Jackson Jr.
Sheet	1	of	3	Attorney Docket Number	0756-7186

					U.S. PATENT DOCUM	ENTS				
Examiner Initials	Cite No.1			ode ²	Name of Patentee or Applicant of Cited Document		ate of Publication of Ci Document MM-DD-YYYY		Columns, Lines, W ges or Relevant Fig	
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(SE)		5,9	923,962	(Ohtani et al.	07	/13/99		$\overline{}$	
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			ОТНЕ	R PRIOR	RART – NON PATENT LITE	RATURE	DOCUMENTS			
Examiner Initials	Cite No. ¹		Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.						T²	
P		Shimokawa et al., "Characterization of High-Efficiency Cast-Si Solar Cell Wafers by MBIC Measurement," Japanese Journal of Applied Physics, Vol. 27, No. 5, May, pp. 751-758, 1988.								
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A			mann Schenk e ceedings, pp. 3		Polymers for Light Em	itting I	Diodes," Eurol	Display '9'	9	

Examiner Signature	Date Considered	2/18/05	
Signature	Constacted	2117100	

^{*}EXAMINER: Initial II reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

¹ Unique citation designation number. 2 Applicant is to place a check mark here if English language Translation is attached.

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Substitute	for form 1449A/PTO		•	Complete if Known		
INFO	RMATION I	nisci	TRUEOL	Application Number	Based on 09/714,891	
	TEMENT BY			Filing Date	November 17, 2000	
SIAI				First Named Inventor	Koji ONO et al.	
	(use as many sheets a	s necesso	עיני)	Group Art Unit	2815	
				Examiner Name	Jerome Jackson Jr.	
Sheet	2	of	3	Attorney Docket Number	0756-7186	

				U.S. PATENT DOCUMEN	TS -			
Examiner Initials	Cite No. ¹	U.S. Patern Document		Name of Patentee or Applicant of Cited	Date of Publication of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
		Number	Kind Code ² (If known)	Document	MM-DD-YYYY			
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		Ottices	Kind Code ¹ Number ⁴ (if known)	Applicant of Cited Document	MM-DD-YYYY	Figures Ap	ppear	Т*		
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2	1	JP	09-293600		11/11/97	1		Abst.		
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17		JР	04-369271		12/22/92			Full		
			OTHER PRIO	R ART – NON PATENT LITE	RATURE DOCUMENTS					
Examiner Initials	Cite No.1			uthor (in CAPITAL LETTERS), journal, serial, symposium, catal publisher, city and/or coun	og, etc.)., date, page(s), volum			T²		
6			Specifications and Drawings for Application Serial No. 09/619,732, "Semiconductor Device and Manufacturing Method Thereof," Filed on July 19, 2000.							
0			Specifications and Drawings for Application Serial No. 09/618,930, "Semiconductor Device and Manufacturing Method Thereof," Filed on July 18, 2000.							
1		Specifications and Drawings for Application Serial No. 09/433,705, "Method of Fabricating a Semiconductor Device," Filed on November 4, 1999.								

Examiner	Date	-/-/-
Signature	Considered	2/19/00

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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Substitute	for form 1449A/PTO			Complete if Known		
INEO	DMATIONI	nic/	TOSHDE	Application Number	Based on 09/714,891	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Filing Date	November 17, 2000	
SIA	EMENI BY	APP	LICANI	First Named Inventor	Koji ONO et al.	
	(use as many sheets	as necess	(מראי)	Group Art Unit	2815	
			Examiner Name	Jerome Jackson Jr.		
Sheet	3	of	3 .	Attorney Docket Number	0756-7186	

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		Number	Kind Code ³ (if known)	Document	MM-DD-YYYY			
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		Ottice	Number ⁴	(if known)	Applicant of Cited Document	MM-DD-YYYY	Figures Appear	14
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D		EP	1 049 167		Yamazaki	11/02/00		Eng.
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Examiner Initials*	Cite No.1				or (in CAPITAL LETTERS), armal, serial, symposium, catalopublisher, city and/or count	og, etc.)., date, page(s), volum		T²
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Signature	Considered	1111-
*EXAMINER: Initial II reference considered.	whether or not citation is in conformance with MPEP 609). Draw line through citation if not in

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